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**Product Fact Sheet** 

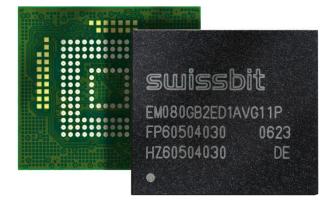
### **Industrial / Automotive** e·MMC Memory

### EM-36 Series

JEDEC e · MMC 5.1 compliant, BGA 153 ball, Enhanced Mode (pSLC) AEC - Q100 Grade 2

Industrial / Automotive Temperature Grade

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## Product Fact Sheet EM-36 Series



#### **Product Summary**

- Capacities: 5 GBytes, 10 GBytes, 20 GBytes, 40 GBytes, 80 GBytes
- Operating Temperature Range¹:
  - Industrial Operating Temperature -40 to 85°C
  - Automotive Operating Temperature -40 to 105°C
     ATS 2 Products2 (Assembly Test Site 2): AEC Q100 Grade 2 certified, not available for 5 GBytes
- Endurance in TeraBytes Written (TBW) @ Max Capacity<sup>2</sup>: up to 4169

#### **Product Features**

- Fully compliant with JEDEC e·MMC 5.1 Standard (JESD84-B51)
- 153-ball BGA, 0.5mm pitch
- 11.5 x 13mm, RoHS compliant
- 3D TLC NAND base technology in Enhanced Mode (pSLC)
- Single enhanced mode partition
- High performance e·MMC 5.1 specification
  - Eleven-wire bus (clock, Data Strobe, 1 bit command, 8 bit data bus) and a hardware reset
  - o Three different data bus width modes: 1-bit (default), 4-bit, and 8-bit
  - o Clock frequencies o-200MHz, High Speed Mode HS400
  - Command Queue Feature according to e・MMC Spec 5.1
  - o Up to 330MB/s sequential read and up to 250MB/s sequential write
- Power Supply: (Low-power CMOS technology)
  - VCCQ 1.7V...1.95V or 2.7V...3.6V e·MMC supply
  - VCC 2.7V...3.6V NAND Flash supply
- Optimized FW algorithms
  - Power-fail data loss protection
  - Wear Leveling technology
    - Equal wear leveling of static and dynamic data. The wear leveling assures that dynamic data as well as static data is balanced evenly across the memory. With that the maximum write endurance of the device is ensured
  - Read Disturb Management
    - The read commands per region are monitored and the content is conditionally refreshed when critical levels have occurred
  - Auto Read Refresh
    - The interruptible background process maintains the user data for Read Disturb effects or Retention degradation due to high temperature effects
  - Diagnostic features with Device Health Report according to e·MMC Spec 5.1, and detailed
     Lifetime Monitor data (Swissbit proprietary, accessible through standard e·MMC commands).
  - o Field Firmware update³ according to e∙MMC Spec 5.1
  - Discard and Sanitize, Trim
  - o Boot Operation Mode and Alternative Boot Operation Mode
  - Replay Protected Memory Block (RPMB)

















<sup>3</sup> The support of In-Field FW update capabilities on host systems is recommended.

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Adequate airflow is required to ensure the temperature does not exceed 85°C (industrial temperature drive)

<sup>&</sup>lt;sup>2</sup> According to JEDEC (JESD47I), the time to write the full TBW is a minimum of 18 months. Higher average daily data volume reduces the specified TBW. The values listed are estimates and are subject to change without notice.

# Product Fact Sheet EM-36 Series



#### High reliability

- o Designed with sophisticated firmware architecture for industrial and embedded markets.
- Enhanced Mode (pSLC) with higher write performance and endurance than 3D TLC configured products (EM-30).
- o Ideal for application like POS/POI, PLC, IoT, gaming, medical and use as general boot medium for embedded applications.
- The product is optimized for long life cycle that requires superior data retention as well as power fail safety.
- Controlled BOM & PCN process

### 1 Order Information for EM-36

#### Table 1: Available Part Numbers

	ATS 1 Gen3 Flash	
	Temperature	
Capacity	Industrial (-40 to 85°C)	Automotive (-40 to 105°C)
	Part Number	Part Number
5 GBytes	SFEM005GB1ED1T0-I-5E-11P-STD	-
10 GBytes	SFEMo10GB1ED1TO-I-5E-11P-STD	-
20 GBytes	SFEM020GB1ED1T0-I-6F-11P-STD	-
40 GBytes	SFEM040GB1ED1T0-I-7G-11P-STD	-
80 GBytes	SFEM080GB1ED1T0-I-8H-11P-STD	-

ATS 1 (Assembly Test Site 1)

#### Table 2: Available Part Numbers

ATS 2 Gen3 Flash			
Temperature			
Industrial (–40 to 85°C)	Automotive (-40 to 105°C)		
Part Number	Part Number		
SFEM005GB2ED1T0-I-5E-11P-STD	SFEM005GB2ED1T0-A-5E-11P-STD		
SFEM010GB2ED1T0-I-5E-11P-STD	SFEM010GB2ED1T0-A-5E-11P-STD		
SFEM020GB2ED1T0-I-6F-11P-STD	SFEM020GB2ED1T0-A-6F-11P-STD		
SFEM040GB2ED1T0-I-7G-11P-STD	SFEM040GB2ED1T0-A-7G-11P-STD		
	Temp Industrial (-40 to 85°C)  Part Number  SFEM005GB2ED1T0-I-5E-11P-STD  SFEM010GB2ED1T0-I-5E-11P-STD  SFEM020GB2ED1T0-I-6F-11P-STD		

ATS 2 (Assembly Test Site 2)

#### Table 3: Available Part Numbers

ATS 2 Gen5 Flash			
Temperature			
Capacity	Industrial (-40 to 85°C)	Automotive (-40 to 105°C)  Part Number	
	Part Number		
20 GBytes	SFEM020GB2ED1TB-I-CE-11P-STD	SFEM020GB2ED1TB-A-CE-11P-STD	
40 GBytes	SFEM040GB2ED1TB-I-EF-11P-STD	SFEM040GB2ED1TB-A-EF-11P-STD	
80 GBytes	SFEM080GB2ED1TB-I-VG-11P-STD	SFEM080GB2ED1TB-A-VG-11P-STD	

ATS 2 (Assembly Test Site 2)



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#### 1.1 System Performance

Gen3 Flash			
System Performance, HS400	Max. reliable mode	Unit	
Burst Data transfer Rate HS400 (max clock 200MHz)	400		
Sequential Read	up to 320	MB/s	
Sequential Write	up to 240		

Gen5 Flash				
System Performance, HS400 Max. reliable mode Unit				
Burst Data transfer Rate HS400 (max clock 200MHz)	400			
Sequential Read	up to 330	MB/s		
Sequential Write	up to 250			

#### 1.2 Current Consumption

Gen3 Flash				
Current Consumption, HS400, Max. Density	Typ. ICCQ current @ VCCQ 1.8V	Typ. ICC current @ VCC 3.3V	Unit	
Write	99	97		
Read	138	108	mA	
Sleep	0.07	0.07		

Gen5 Flash				
Current Consumption, HS400, Max. Density	Typ. ICCQ current @ VCCQ 1.8V	Typ. ICC current @ VCC 3.3V	Unit	
Write	102	104		
Read	142	105	mA	
Sleep	0.06	0.04		

#### 1.3 Physical Dimensions

Physical Dimensions	Value	Unit
Length	13±0.1	
Width	11.5±0.1	mm
Thickness	1.2 max.	

#### 1.4 Recommended Temperature Conditions

Parameter	Min.	Тур.	Max.	Unit
Industrial Operating Temperature	-40	25	85	°C
Automotive Operating Temperature	-40	25	105	°C

<sup>\*</sup> High temperature storage without operation reduces the data retention, in operation the data will be refreshed, if data error issues were detected

For more information on e·MMC interface, please visit JEDEC homepage (www.jedec.org)

#### Why Swissbit?

Swissbit is focused on the design, development, manufacture, and support of leading edge memory and storage solutions for the worldwide OEM/ODM marketplace. As a global supplier, Swissbit recognizes and addressees the higher level of application requirements of today's industrial, Netcom, and automotive customers by providing best-in-class products and services, with uncompromised attention to driving overall value and quality.

